## Insulated Gen 2 Schottky Rectifier Module, 250 A



SOT-227

| PRIMARY CHARACTERISTICS |  |
| :---: | :---: |
| $\mathrm{I}_{\mathrm{F}(\mathrm{AV})}$ per module at $\mathrm{T}_{\mathrm{C}}=106^{\circ} \mathrm{C}$ | 250 A |
| $\mathrm{~V}_{\mathrm{R}}$ | 200 V |
| $\mathrm{~V}_{\mathrm{FM}}$ at $200 \mathrm{~A}, \mathrm{~T}_{\mathrm{C}}=25^{\circ} \mathrm{C}$ | 1.0 V |
| Package | SOT-227 |
| Circuit configuration | Two separate diodes, <br> parallel pin-out |

## FEATURES

- Max. $\mathrm{T}_{\mathrm{J}}=175^{\circ} \mathrm{C}$
- Two fully independent diodes

- Fully insulated package
- Trench MOS Barrier Schottky technology
- Ultra low forward voltage drop
- Optimized for power conversion: welding and industrial SMPS applications
- Easy to use and parallel
- Industry standard outline
- UL approved file E78996

FII

- Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912


## DESCRIPTION

The VS-QA250FA20 insulated modules integrate two state of the art Trench MOS Schottky technology rectifiers in the compact, industry standard SOT-227 package.
These devices are thus intended for high frequency converters and switching power supplies.

MAJOR RATINGS AND CHARACTERISTICS

| SYMBOL | CHARACTERISTICS | VALUES | UNITS |
| :--- | :--- | :---: | :---: |
| $\mathrm{V}_{\mathrm{F}}$ | $\mathrm{T}_{J}=125^{\circ} \mathrm{C}$ | 1.09 | V |
| $\mathrm{~T}_{J}$ | Range | -55 to +175 | ${ }^{\circ} \mathrm{C}$ |

ABSOLUTE MAXIMUM RATINGS $\left(T_{C}=25^{\circ} \mathrm{C}\right.$ unless otherwise specified)

| PARAMETER | SYMBOL | TEST CONDITIONS | VALUES | UNITS |
| :--- | :---: | :--- | :---: | :---: |
| Maximum average forward current per module | $\mathrm{I}_{\mathrm{F}(\mathrm{AV})}$ | $\mathrm{T}_{\mathrm{C}}=106^{\circ} \mathrm{C}$ | 250 | A |
| Maximum cathode to anode voltage | $\mathrm{V}_{\mathrm{R}}$ |  | 200 | N |
| Maximum continuous forward current per diode | $\mathrm{I}_{\mathrm{F}}$ | $\mathrm{T}_{\mathrm{C}}=95^{\circ} \mathrm{C}$ | 183 | A |
| Maximum single pulse forward current per diode | $\mathrm{I}_{\mathrm{FSM}}$ | $\mathrm{T}_{\mathrm{C}}=175^{\circ} \mathrm{C}, \mathrm{t}=6 \mathrm{~ms}$, square | 900 |  |
| Maximum power dissipation per diode | $\mathrm{P}_{\mathrm{D}}$ | $\mathrm{T}_{\mathrm{C}}=95^{\circ} \mathrm{C}$ | 182 | W |
| Non-repetitive avalanche energy per diode | $\mathrm{E}_{\mathrm{AS}}$ | $\mathrm{T}_{\mathrm{J}}=25^{\circ} \mathrm{C}, \mathrm{I}_{\mathrm{AS}}=19 \mathrm{~A}, \mathrm{~L}=10 \mathrm{mH}$ | 1800 | W |
| RMS isolation voltage | $\mathrm{V}_{\text {ISOL }}$ | Any terminal to case, $\mathrm{t}=1 \mathrm{minute}$ | 2500 | V |
| Operating junction and storage temperatures | $\mathrm{T}_{\mathrm{J}}, \mathrm{T}_{\mathrm{Stg}}$ |  | -55 to +175 | ${ }^{\circ}{ }^{\circ} \mathrm{C}$ |

## ELECTRICAL SPECIFICATIONS PER DIODE ( $\mathrm{T}_{J}=25^{\circ} \mathrm{C}$ unless otherwise specified)

| PARAMETER | SYMBOL | TEST CONDITIONS | MIN. | TYP. | MAX. | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Cathode to anode breakdown voltage | $V_{B R}$ | $\mathrm{I}_{\mathrm{R}}=2 \mathrm{~mA}$ | 200 | - | - | V |
| Forward voltage | $V_{\text {FM }}$ | $\mathrm{I}_{\mathrm{F}}=200 \mathrm{~A}$ | - | 1.0 | 1.2 |  |
|  |  | $\mathrm{I}_{\mathrm{F}}=200 \mathrm{~A}, \mathrm{~T}_{J}=125^{\circ} \mathrm{C}$ | - | 0.89 | 1.09 |  |
| Reverse leakage current | IRM | $\mathrm{V}_{\mathrm{R}}=200 \mathrm{~V}$ | - | 13 | 90 | $\mu \mathrm{A}$ |
|  |  | $\mathrm{T}_{\mathrm{J}}=125^{\circ} \mathrm{C}, \mathrm{V}_{\mathrm{R}}=\mathrm{V}_{\mathrm{R}}$ rated | - | 14 | - | mA |
| Junction capacitance | $\mathrm{C}_{\text {T }}$ | $\mathrm{V}_{\mathrm{R}}=200 \mathrm{~V}$ | - | 380 | - | pF |


| DYNAMIC RECOVERY CHARACTERISTICS ( $\mathrm{T}_{J}=25^{\circ} \mathrm{C}$ unless otherwise specified) |  |  |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| PARAMETER | SYMBOL | TEST CONDITIONS |  | MIN. | TYP. | MAX. | UNITS |
| Reverse recovery time | $\mathrm{trrr}^{\text {r }}$ | $\mathrm{T}_{\mathrm{J}}=25^{\circ} \mathrm{C}$ | $\begin{aligned} & \mathrm{I}_{\mathrm{F}}=50 \mathrm{~A} \\ & \mathrm{dl}_{\mathrm{F}} / \mathrm{dt}=200 \mathrm{~A} / \mu \mathrm{s} \\ & \mathrm{~V}_{\mathrm{R}}=100 \mathrm{~V} \end{aligned}$ | - | 54 | - |  |
|  |  | $\mathrm{T}_{\mathrm{J}}=125^{\circ} \mathrm{C}$ |  | - | 67 | - | ns |
| Peak recovery current | IRRM | $\mathrm{T}_{\mathrm{J}}=25^{\circ} \mathrm{C}$ |  | - | 6 | - | A |
|  |  | $\mathrm{T}_{\mathrm{J}}=125^{\circ} \mathrm{C}$ |  | - | 8.4 | - |  |
| Reverse recovery charge | $\mathrm{Q}_{\mathrm{rr}}$ | $\mathrm{T}_{\mathrm{J}}=25^{\circ} \mathrm{C}$ |  | - | 165 | - | nC |
|  |  | $\mathrm{T}_{\mathrm{J}}=125^{\circ} \mathrm{C}$ |  | - | 296 | - |  |


| PARAMETER | SYMBOL | TEST CONDITIONS | MIN. | TYP. | MAX. | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Junction to case, single leg conducting | $\mathrm{R}_{\mathrm{th} \mathrm{JC}}$ |  | - | - | 0.44 | º'W |
| Junction to case, both leg conducting |  |  | - | - | 0.22 |  |
| Case to heatsink | $\mathrm{R}_{\text {thCs }}$ | Flat, greased surface | - | 0.1 | - |  |
| Weight |  |  | - | 30 | - | g |
| Mounting torque |  | Torque to terminal | - | - | 1.1 (9.7) | Nm (lbf.in) |
|  |  | Torque to heatsink | - | - | 1.8 (15.9) | Nm (lbf.in) |
| Case style |  |  | SOT-227 |  |  |  |



Fig. 1 - Typical Forward Voltage Drop vs. Instantaneous Forward Current (Per Diode)


Fig. 2 - Typical Reverse Current vs. Reverse Voltage (Per Diode)


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Diode)


Fig. 4 - Maximum Thermal Impedance $Z_{\text {thJc }}$ Characteristics (Per Diode)

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Fig. 5 - Maximum Current Rating Capability (Per Diode)


Fig. 6 - Forward Power Loss Characteristics (Per Diode)


Fig. 7 - Typical Reverse Recovery Charge vs. $\mathrm{dl}_{\mathrm{F}} / \mathrm{dt}$ (Per Diode)


Fig. 8 - Typical Reverse Recovery Time vs. $\mathrm{dl}_{\mathrm{F}} / \mathrm{dt}$ (Per Diode)


Fig. 9 - Typical Reverse Recovery Current vs. $\mathrm{dl}_{\mathrm{F}} / \mathrm{dt}$ (Per Diode)


Fig. 10 - Reverse Recovery Parameter Test Circuit


Fig. 11 - Reverse Recovery Waveform and Definitions

## ORDERING INFORMATION TABLE



| 1 | - | Vishay Semiconductors product |
| :--- | :--- | :--- |
| 2 | - | Schottky technologies |
| 3 | - | Present silicon generation |
| 4 | - | Current rating $(250=250 \mathrm{~A})$ |
| 5 | - | Circuit configuration $(2$ separate diodes, parallel pin-out $)$ |
| 6 | - | Package indicator $($ SOT- 227 standard insulated base $)$ |
| 7 | - | Voltage rating $(20=200 \mathrm{~V})$ |

Quantity per tube is 10 , M4 screw and washer included

| CIRCUIT CONFIGURATION |  |  |
| :---: | :---: | :---: |
| CIRCUIT | CIRCUIT CONFIGURATION CODE | CIRCUIT DRAWING |
| 2 separate diodes, parallel pin-out | F |  |


| LINKS TO RELATED DOCUMENTS |  |
| :--- | :--- |
| Dimensions | $\underline{w w w . v i s h a y . c o m / d o c ? 95423 ~}$ |
| Packaging information | $\underline{w w w . v i s h a y . c o m / d o c ? 95425 ~}$ |

## SOT-227 Generation 2

DIMENSIONS in millimeters (inches)


## Note

- Controlling dimension: millimeter


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